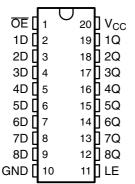
SCBS687H - MAY 1997 - REVISED SEPTEMBER 2003

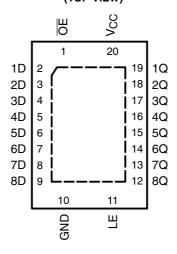
- **Support Mixed-Mode Signal Operation** (5-V Input and Output Voltages With 3.3-V V_{CC})
- **Support Unregulated Battery Operation** Down to 2.7 V
- Typical V_{OLP} (Output Ground Bounce) <0.8 V at $V_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- Ioff and Power-Up 3-State Support Hot Insertion

- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 500 mA Per JESD 17
- **ESD Protection Exceeds JESD 22**
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)

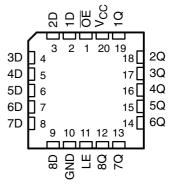
SN54LVTH573...J OR W PACKAGE SN74LVTH573 . . . DB, DW, NS, **OR PW PACKAGE** (TOP VIEW)



SN74LVTH573 . . . RGY PACKAGE (TOP VIEW)



SN54LVTH573 . . . FK PACKAGE (TOP VIEW)



description/ordering information

ORDERING INFORMATION

T _A	PACKAGE	t	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QFN – RGY	Tape and reel	SN74LVTH573RGYR	LXH573
	COIC DW	Tube	SN74LVTH573DW	LVTH573
	SOIC - DW	Tape and reel	SN74LVTH573DWR	LVTH573
	SOP - NS	Tape and reel	SN74LVTH573NSR	LVTH573
-40°C to 85°C	SSOP – DB	Tape and reel	SN74LVTH573DBR	LXH573
	TOOOD DW	Tube	SN74LVTH573PW	1.7/1570
	TSSOP – PW	Tape and reel	SN74LVTH573PWR	LXH573
	VFBGA – GQN	T	SN74LVTH573GQNR	1.7/1/570
	VFBGA – ZQN (Pb-free)	Tape and reel	SN74LVTH573ZQNR	LXH573
	CDIP – J	Tube	SNJ54LVTH573J	SNJ54LVTH573J
–55°C to 125°C	CFP – W	Tube	SNJ54LVTH573W	SNJ54LVTH573W
	LCCC - FK	Tube	SNJ54LVTH573FK	SNJ54LVTH573FK

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



1

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description/ordering information (continued)

These octal latches are designed specifically for low-voltage (3.3-V) V_{CC} operation, but with the capability to provide a TTL interface to a 5-V system environment.

The eight latches of the 'LVTH573 devices are transparent D-type latches. While the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is taken low, the Q outputs are latched at the logic levels set up at the D inputs.

A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without need for interface or pullup components.

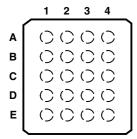
OE does not affect the internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

These devices are fully specified for hot-insertion applications using I_{off} and power-up 3-state. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

SN74LVTH573 . . . GQN OR ZQN PACKAGE (TOP VIEW)



terminal assignments

	1	2	3	4
A	1D	ŌĒ	V _{CC}	1Q
В	3D	3Q	2D	2Q
С	5D	4D	5Q	4Q
D	7D	7Q	6D	6Q
Ε	GND	8D	LE	8Q

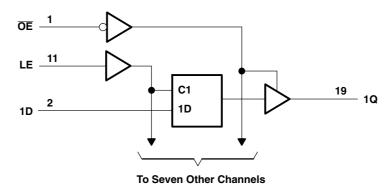
FUNCTION TABLE (each latch)

	INPUTS								
OE	LE	D	Q						
L	Н	Н	Н						
L	Н	L	L						
L	L	Χ	Q_0						
Н	X	Χ	Z						



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logic diagram (positive logic)



Pin numbers shown are for the DB, DW, FK, J, NS, PW, RGY, and W packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}		–0.5 V to 4.6 V
Input voltage range, V _I (see Note 1)		
Voltage range applied to any output in t	he high-impedance	
or power-off state, V _O (see Note 1)		–0.5 V to 7 V
Voltage range applied to any output in t	he high state, V_O (see Note 1)	0.5 V to V _{CC} + 0.5 V
Current into any output in the low state,	I _O : SN54LVTH573	96 mA
	SN74LVTH573	128 mA
Current into any output in the high state	, I _O (see Note 2): SN54LVTH573	48 mA
	SN74LVTH573	64 mA
Input clamp current, $I_{IK}(V_I < 0)$		–50 mA
Output clamp current, $I_{OK}(V_O < 0)$		–50 mA
Package thermal impedance, θ _{JA} (see I	Note 3): DB package	70°C/W
(see	Note 3): DW package	58°C/W
(see	Note 3): GQN/ZQN package	78°C/W
(see	Note 3): NS package	60°C/W
(see	Note 3): PW package	83°C/W
(see	Note 4): RGY package	37°C/W
Storage temperature range, T _{stq}		–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

- 2. This current flows only when the output is in the high state and $V_O > V_{CC}$.
- 3. The package thermal impedance is calculated in accordance with JESD 51-7.
- 4. The package thermal impedance is calculated in accordance with JESD 51-5.



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recommended operating conditions (see Note 5)

			SN54LV	TH573	SN74LV	TH573	
			MIN	MAX	MIN	MAX	UNIT
V _{CC}	Supply voltage		2.7	3.6	2.7	3.6	V
V _{IH}	High-level input voltage		2		2		V
V _{IL}	Low-level input voltage			0.8		0.8	V
VI	Input voltage			5.5		5.5	V
I _{OH}	High-level output current			-24		-32	mA
I _{OL}	Low-level output current			48		64	mA
Δt/Δν	Input transition rise or fall rate	Outputs enabled		10		10	ns/V
$\Delta t/\Delta V_{CC}$	Power-up ramp rate		200		200		μs/V
T _A	Operating free-air temperature		-55	125	-40	85	°C

NOTE 5: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

			AND TIONS	SN	54LVTH5	573	SN7	4LVTH5	73	
PA	RAMETER	TEST CO	ONDITIONS	MIN	TYP†	MAX	MIN	TYP†	MAX	UNIT
V_{IK}		$V_{CC} = 2.7 \text{ V},$	$I_I = -18 \text{ mA}$			-1.2			-1.2	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V},$	$I_{OH} = -100 \mu A$	V _{CC} -0.	2		V _{CC} -0.2	2		
V		$V_{CC} = 2.7 \text{ V},$	$I_{OH} = -8 \text{ mA}$	2.4			2.4			
V _{OH}		V 0.V	$I_{OH} = -24 \text{ mA}$	2						V
		V _{CC} = 3 V	$I_{OH} = -32 \text{ mA}$				2			
		V 0.7.V	$I_{OL} = 100 \mu A$			0.2			0.2	
		V _{CC} = 2.7 V	I _{OL} = 24 mA			0.5			0.5	
.,			I _{OL} = 16 mA			0.4			0.4	.,
V_{OL}			I _{OL} = 32 mA			0.5			0.5	V
		V _{CC} = 3 V	$I_{OL} = 48 \text{ mA}$			0.55				
			I _{OL} = 64 mA						0.55	
	Control innuito	$V_{CC} = 0 \text{ or } 3.6 \text{ V},$	$V_1 = 5.5 \text{ V}$			10			10	
	Control inputs	$V_{CC} = 3.6 \text{ V},$	$V_I = V_{CC}$ or GND			±1			±1	^
I _I	Data innuta	V _{CC} = 3.6 V	$V_I = V_{CC}$			1			1	μΑ
	Data inputs	V _{CC} = 3.6 V	$V_I = 0$			-5			-5	
I _{off}		$V_{CC} = 0$,	V_I or $V_O = 0$ to 4.5 V						±100	μΑ
		V _{CC} = 3 V	$V_1 = 0.8 V$	75			75			
I _{I(hold)}	Data inputs	V _{CC} = 3 V	V _I = 2 V	-75			-75			μΑ
		$V_{CC} = 3.6 V^{\ddagger}$,	$V_1 = 0 \text{ to } 3.6 \text{ V}$						±500	
I _{OZH}		$V_{CC} = 3.6 \text{ V},$	V _O = 3 V			5			5	μΑ
l _{OZL}		$V_{CC} = 3.6 \text{ V},$	$V_0 = 0.5 \text{ V}$			-5			-5	μΑ
I _{OZPU}		$V_{CC} = 0$ to 1.5 V, $V_{O} = 0$ $\overline{OE} = \text{don't care}$	0.5 V to 3 V,			±100*			±100	μΑ
I _{OZPD}		V_{CC} = 1.5 V to 0, V_O = 0 \overline{OE} = don't care	0.5 V to 3 V,			±100*			±100	μΑ
		V _{CC} = 3.6 V,	Outputs high			0.19			0.19	
I _{CC}		$I_{O}=0$,	Outputs low			5			5	mA
		$V_I = V_{CC}$ or GND	Outputs disabled			0.19			0.19	
Δl _{CC} §		$V_{CC} = 3 \text{ V to } 3.6 \text{ V, One}$ Other inputs at V_{CC} or 0				0.2			0.2	mA
C _i		V _I = 3 V or 0			3			3		pF
Co		V _O = 3 V or 0			7			7		pF
		•					-			

^{*}On products compliant to MIL-PRF-38535, this parameter is not production tested.

 $^{^{\}dagger}$ All typical values are at V_{CC} = 3.3 V, T_{A} = 25°C.

[‡] This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

[§] This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{CC} or GND.

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timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

			SN54L\	/TH573			SN74L\	/TH573		
		V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 2.7 V		V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 2.7 V		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _w	Pulse duration, LE high	3		3		3		3		ns
t _{su}	Setup time, data before LE↓	0.7		0.6		0.7		0.6		ns
t _h	Hold time, data after LE↓	1.5		1.7		1.5		1.7		ns

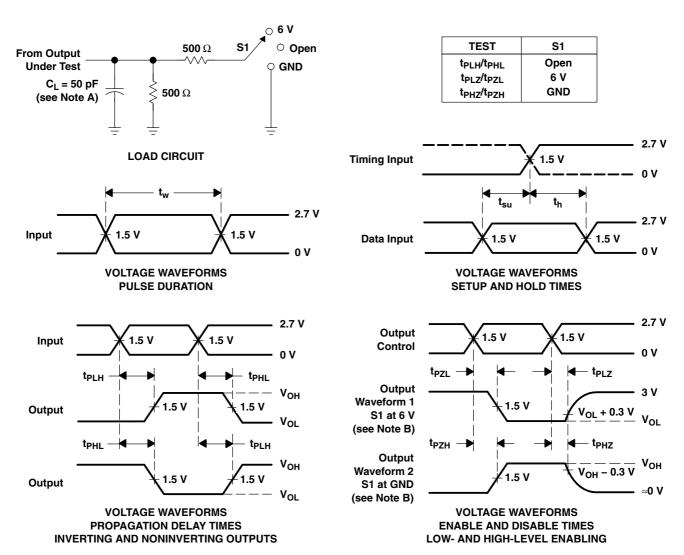
switching characteristics over recommended free-air temperature, C_L = 50 pF (unless otherwise noted) (see Figure 1)

				SN54L\	/TH573							
PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 3.3 \text{ V} \\ \pm 0.3 \text{ V} $ $V_{CC} = 2.7 \text{ V}$			_{CC} = 3.3 \ ± 0.3 V	٧	V _{CC} = 2.7 V		UNIT		
			MIN	MAX	MIN	MAX	MIN	TYP†	MAX	MIN	MAX	
t _{PLH}	1	0	1.4	4.1		4.7	1.5	2.6	3.9		4.5	
t _{PHL}	D	Q	1.4	4.5		4.8	1.5	2.9	3.9		4.5	ns
t _{PLH}	LE	0	1	4.4		5.4	1.9	2.9	4.2		4.9	2
t _{PHL}	LE	Q	1.4	4.4		5.1	1.9	2.9	4.2		4.9	ns
t _{PZH}	ŌĒ	0	1.4	5.2		6.2	1.5	3.2	5.1		5.9	
t _{PZL}	OE	Q	1.4	5.2		6.2	1.5	3.9	5.1		5.9	ns
t _{PHZ}	<u> </u>	0	1.2	5.4		5.7	2	3.5	4.9		5.5	2
t _{PLZ}	ŌĒ	Q	1	5.2		5.2	2	3.2	4.6		4.9	ns

[†] All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.



PARAMETER MEASUREMENT INFORMATION



NOTES: A. C₁ includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_{O} = 50 Ω , $t_{f} \leq$ 2.5 ns, $t_{f} \leq$ 2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms



5-Sep-2011

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
5962-9583101Q2A	ACTIVE	LCCC	FK	20	1	TBD	Call TI	Call TI	
5962-9583101QRA	ACTIVE	CDIP	J	20	1	TBD	Call TI	Call TI	
5962-9583101QSA	ACTIVE	CFP	W	20	1	TBD	Call TI	Call TI	
SN74LVTH573DBLE	OBSOLETE	SSOP	DB	20		TBD	Call TI	Call TI	
SN74LVTH573DBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH573DBRE4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH573DBRG4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH573DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH573DWE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH573DWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH573DWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH573DWRE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH573DWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH573NSR	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH573NSRE4	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH573NSRG4	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH573PW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH573PWE4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	





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Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
SN74LVTH573PWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH573PWLE	OBSOLETE	TSSOP	PW	20		TBD	Call TI	Call TI	
SN74LVTH573PWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH573PWRE4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH573PWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH573RGYR	ACTIVE	VQFN	RGY	20	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
SN74LVTH573RGYRG4	ACTIVE	VQFN	RGY	20	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
SNJ54LVTH573FK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	
SNJ54LVTH573J	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	
SNJ54LVTH573W	ACTIVE	CFP	W	20	1	TBD	Call TI	N / A for Pkg Type	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



PACKAGE OPTION ADDENDUM

5-Sep-2011

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN54LVTH573, SN74LVTH573:

● Enhanced Product: SN74LVTH573-EP, SN74LVTH573-EP

Military: SN54LVTH573

NOTE: Qualified Version Definitions:

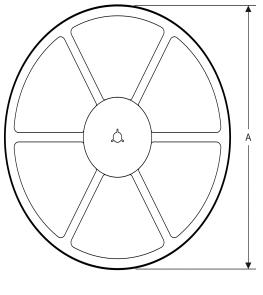
- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

14-Jul-2012 www.ti.com

TAPE AND REEL INFORMATION

REEL DIMENSIONS





TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVTH573DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74LVTH573DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
SN74LVTH573NSR	SO	NS	20	2000	330.0	24.4	8.2	13.0	2.5	12.0	24.0	Q1
SN74LVTH573PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74LVTH573RGYR	VQFN	RGY	20	3000	330.0	12.4	3.8	4.8	1.6	8.0	12.0	Q1

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*All dimensions are nominal

7. di di nenolono di e nomina							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVTH573DBR	SSOP	DB	20	2000	367.0	367.0	38.0
SN74LVTH573DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74LVTH573NSR	SO	NS	20	2000	367.0	367.0	45.0
SN74LVTH573PWR	TSSOP	PW	20	2000	367.0	367.0	38.0
SN74LVTH573RGYR	VQFN	RGY	20	3000	367.0	367.0	35.0

14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

W (R-GDFP-F20)

CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within Mil-Std 1835 GDFP2-F20



FK (S-CQCC-N**)

LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004



DW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- G. Package complies to JEDEC MO-241 variation BA.



RGY (R-PVQFN-N20)

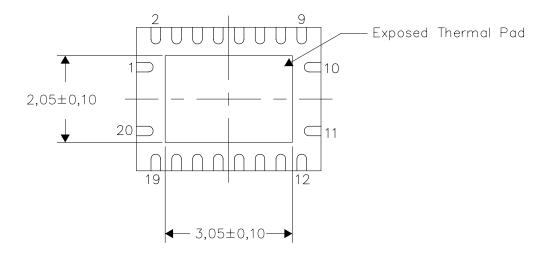
PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

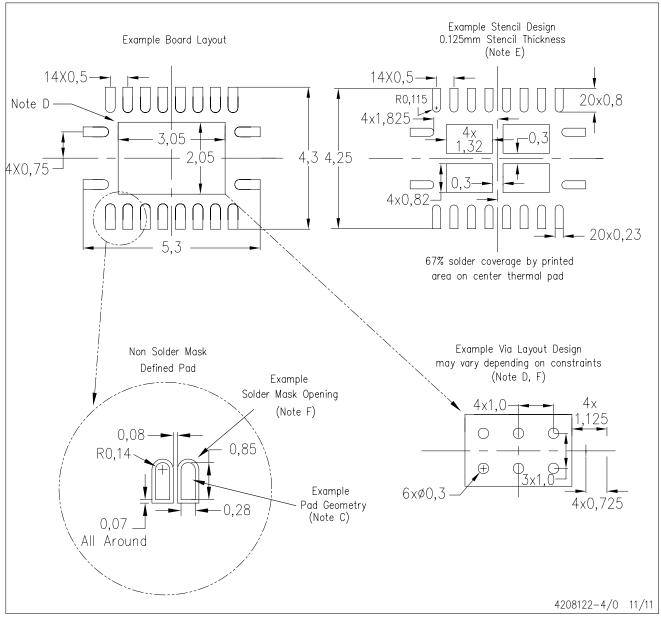
4206353-4/0 11/11

NOTE: All linear dimensions are in millimeters



RGY (R-PVQFN-N20)

PLASTIC QUAD FLATPACK NO-LEAD



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

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